			220324002.1		PCN Date:		ate:	March 30, 2022	
				b site (RFAB) using additional Assembly					ology, Die Revision, elect devices
Customer	Contact:		PC	<u> V Manager</u>		Dep	ot:		Quality Services
Proposed 1 st Ship Date:						Estimated Sample Availability:		nple	Date provided at sample request.
Change T	ype:								
🛛 Assen	nbly Site		Assembly Process			\boxtimes	Assembly Materials		
Desig	n		\boxtimes	Electrical Specifica	ation 📃 Mech		Mech	anical Specification	
Test S	Site		Packing/Shipping/Labeling		ļ		Test Process		
Wafer Bump Site			Wafer Bump Material				Wafer Bump Process		
Wafer Fab Site		Wafer Fab Materials			\boxtimes	Wafe	r Fab Process		
				Part number chan	ge				

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (RFAB, LBC7) and assembly (MLA, HFTF) site/BOM options for selected devices as listed below in the product affected section.

	Current Fa	b Site	New Fab Site					
Fab Site	Fab Site Process Wafer Diameter			Fab Site Process Wafer Diameter				
DL-LIN	LBC3S	150 mm	RFAB	LBC7	200 mm			
DL-LIN	LBC3S	200 mm	RFAD	LDC7	300 mm			

The die was also changed as a result of the process change.

The datasheets will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The link to the revised datasheet is available in the table below.



SN65HVD3082E, SN75HVD3082E, SN65HVD3085E, SN65HVD3088E SLLS562M – AUGUST 2009 – REVISED FEBRUARY 2022

С	Changes from Revision L (November 2021) to Revision M (February 2022)						
•	Added storage temperature T _{stg} to Absolute Maximum Ratings table	4					
	Changed the Thermal Information, SN65HVD308xE table						

TEXAS INSTRUMENTS	SN65HVD10, SN65HVD11, SN65HVD12 SN75HVD10, SN75HVD11, SN75HVD12 SLLS505P – FEBRUARY 2002 – REVISED FEBRUARY 2022
Channes from Devision O (February 2017)	to Devision D (February 2022)

Changes from Revision O (February 2017) to Revision P (February 2022) Page

Product Folder	Current Datasheet Number	New Datasheet Number	Link to full datasheet
SN65HVD3082E	SLLS562L	SLLS562M	http://www.ti.com/product/SN65HVD3088E
SN65HVD10	SLLS5050	SLLS505P	http://www.ti.com/product/SN65HVD10

Construction differences are noted below:

Group 1 device (FMX to MLA)

No material differences between sites

Group <u>2 device (ASESH, HNA to HFTFAT)</u>

	ASESH	HNA	HFTFAT
Lead finish	NiPdAuAg	NiPdAu	Matte Sn
Bond wire/diameter	Au, Cu	Au	Cu
Mount Compound	EY1000063	400180	A-18
Mold Compound	EN2000515	450179	R-30

Upon expiry of this PCN TI will combine lead free solutions in a single <u>standard part number</u>, for example; <u>SN65HVD3085EDGKR</u> – can ship with both Matte Sn and NiPdAu.

Example:

- Customer order for 7500units of SN65HVD3085EDGKR with 2500 units SPQ (Standard Pack Quantity per Reel).
- TI can satisfy the above order in one of the following ways.
 - I. 3 Reels of NiPdAu finish.
 - II. 3 Reels of Matte Sn finish
 - III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish.
 - IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.

Tube versions of the devices are included in EOL notice PDN# 20220324003.3

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
🛛 No Change	🛛 No Change	🛛 No Change	🛛 No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
DL-LIN	DLN	USA	Dallas
RFAB	RFB	USA	Richardson

Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]
А, В	-

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City	
FMX	MEX	MEX	Aguascalientes	
ASESH	ASH	CHN	Shanghai	
HNA	HNT	THA	Ayutthaya	
HFTFAT	HFT	CHN	Hefei	
MLA	MLA	MYS	Kuala Lumpur	
TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 20: MSL 2 /260C/1 YEAR SEAL	G4 = (1P G4 (0) DT (44) (31)	Matte Sn NiPdAu) SN74LS07NSR) 2000 (D) 0336 T) LOT: 3959047MLA		
TEXAS	G3 = G4 = G4 (1P (Q) 9/04 (31 (4P) (2P)	Matte Sn NiPdAu) SN74LS07NSR) 2000 (D) 0336		
TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q: MSL '2 /260C/1 YEAR SEAL MSL 1 /235C/UNLIM 03/2 DPT: JEFM: 39	G3 = G4 = G4 (1P (Q) 9/04 (31 (4P) (2P)	Matte Sn NiPdAu) SN74LS07NSR) 2000 (D) 0336 T)LOT: 3959047MLA) TKY (1T) 7523483512 REV: (V) 0053517) CS0: SHE (21L) CC0:USA		
TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /2600C/1 YEAR SEAL MSL 1 /235C/UNLIM 03/2 OPT: 39 BL: 5A (L)T0:17 roduct Affected:	G3 = G4 = G4 = (1P (Q (Q (31 (31 (4W (2P)) (20L (22L	Matte Sn NiPdAu) SN74LS07NSR) 2000 (D) 0336 T)LOT: 3959047MLA) TKY (1T) 7523483S12 REV: (V) 0053517) CS0: SHE (21L) CC0:USA) AS0: MLA (23L) AC0: MYS	ly Sito):	
TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /2600C/1 YEAR SEAL MSL 1 /235C/UNLIM 03/2 OPT: 39 BL: 5A (L)T0:17 roduct Affected:	G3 = G4 = G4 (1P (Q) 9/04 (31 (4P) (2P)	Matte Sn NiPdAu) SN74LS07NSR) 2000 (D) 0336 T) LOT: 3959047MLA) TKY (1T) 7523483S12 REV: (V) 0053517) CS0: SHE (21L) CC0:USA) AS0: MLA (23L) AC0: MYS n + FMX to MLA Assemb	ly Site): SN65HVD3088EDR	
TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /260C/1 YEAR SEAL MSL 1 /235C/UNLIM 03/2 OPT: TTEM: 39 BL: 5A (L)TO:17 FODUCT Affected: TOUD 1 Device List (G3 = G4 = (1P (Q) (Q) (Q) (Q) (Q) (Q) (Q) (Q) (Q) (Q)	Matte Sn NiPdAu) \$N74L\$07N\$R) 2000 (D) 0336 T)L0T: 3959047MLA) TKY (1T) 7523483S12 REV: (V) 0053517) CS0: SHE (21L) CC0:USA) AS0: MLA (23L) AC0: MYS n + FMX to MLA Assemb SN65HVD12DR S		

Qualification Report

Approve Date 01-Dec-2021

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

TypeTest Name / ConditionDurationQual Device: SNSSHVD10QDRQual Device: SNSSHVD12DRQBS Process Reference: TPS51217DSCQBS Package Reference: TPS51217DSCQBS Package Reference: TCAN1044VD01 (PG2.0)QBS Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBS Package Reference: TSS1217DSCQBS Package Reference: TPS51217DSCQBS Package Reference: TPS51217DSCQBS Package Reference: TCAN1044VD01 (PG2.0)QBS Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBS Package Reference: TPS51217DSCQBS Package Reference: TPS51217DSCQBS Package Reference: TSS1217DSCQBS Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TPS51217DSCQBS Package Reference: TSS1217DSCQBS Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TCAN1044VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF Package Reference: TCAN104VD01 (PG1.11PG1.0)QBF P								
CDM ESD - CDM 1500 V 1/3/0 1/3/0 - - - ED Electrical Characterization Per Datasheet Parameters Pass Pass Pass - - - - HAST Biased HAST, 130C/85%RH 96 Hours - - 3/231/0 1/77/0 2/154/0 HBM ESD - HBM (All Pins) 4000 V 1/3/0 1/3/0 - - - - HBM ESD - HBM (Bus Pins Only) 16000 V 1/3/0 1/3/0 -	Туре		Duration		-	Reference:	Reference: TCAN1044VDQ1	Reference: TCAN1044VD Q1
ED Electrical Characterization Per Datasheet Parameters Pass Pass - - - HAST Biased HAST, 130C/85%RH 96 Hours - - 3/231/0 1/77/0 2/154/0 HBM ESD - HBM (All Pins) 4000 V 1/3/0 1/3/0 - - - HBM ESD - HBM (All Pins) 4000 V 1/3/0 1/3/0 - - - HBM ESD - HBM (Bus Pins Only) 16000 V 1/3/0 1/3/0 - - - HTOL Life Test, 125C 1000 Hours - - 3/231/0 - - HTOL Life Test, 135C 635 Hours - - 3/231/0 - - HTSL Storage Bake, 175C 500 Hours - - 3/231/0 - - HTSL Storage Bake, 170C 420 Hours - - 3/231/0 - - LU Latch-up (Per JESD78) 1/6/0 1/6/0 - <td< td=""><td>AC</td><td>Autoclave 121C</td><td>96 Hours</td><td>-</td><td>-</td><td>3/231/0</td><td>1/77/0</td><td>2/154/0</td></td<>	AC	Autoclave 121C	96 Hours	-	-	3/231/0	1/77/0	2/154/0
$ \begin{array}{ c c c c c c } \hline Electrical \\ Characterization \\ Parameters \\ Parameters \\ Pass \\ Pas \\ Pas$	CDM	ESD - CDM	1500 V	1/3/0	1/3/0	-	-	-
HAST 130C/85%RH 96 Hours - - 3/231/0 1/77/0 2/154/0 HBM ESD - HBM (All Pins) 4000 V 1/3/0 1/3/0 - - - - HBM ESD - HBM (Bus Pins Only) 16000 V 1/3/0 1/3/0 -	ED		Datasheet	Pass	Pass	-	-	-
HBM Pins) 4000 V 1/3/0 1/3/0 - - - - HBM ESD - HBM (Bus Pins Only) 16000 V 1/3/0 1/3/0 -	HAST		96 Hours	-	-	3/231/0	1/77/0	2/154/0
HBM Pins Only) 16000 V 1/3/0 1/3/0 - - - - HTOL Life Test, 125C 1000 Hours - - 3/231/0 - 1/77/0 2/154/0 HTOL Life Test, 135C 635 Hours - - 3/231/0 - - - HTSL Storage Bake 500 Hours - - - 1/45/0 2/90/0 175C - - - - 1/45/0 2/90/0 HTSL Storage Bake 500 Hours - - - 1/45/0 2/90/0 HTSL Storage Bake, 175C - - - - 1/45/0 2/90/0 HTSL Storage Bake, 170C -	нвм		4000 V	1/3/0	1/3/0	-	-	-
HTOL Life Test, 135C 635 Hours - - 3/231/0 - - High Temp - - 3/231/0 -<	нвм		16000 V	1/3/0	1/3/0	-	-	-
High Temp Storage Bake 175C 500 Hours - - - 1/45/0 2/90/0 HTSL Storage Bake 175C 500 Hours - - - 1/45/0 2/90/0 HTSL Storage Bake, 170C 420 Hours - - 3/231/0 - - LU Latch-up (Per JESD78) 1/6/0 1/6/0 - - - TC Temperature Cycle, -65/150C 500 Cycles - - 3/231/0 1/77/0 2/154/0 WBP Bond Pull Wires 1/76/0 1/76/0 - 1/30/0 2/60/0	HTOL	Life Test, 125C	1000 Hours	-	-	-	1/77/0	2/154/0
HTSL Storage Bake 175C 500 Hours - - 1/45/0 2/90/0 HTSL 175C - - - 1/45/0 2/90/0 HTSL High Temp Storage Bake, 170C 420 Hours - - 3/231/0 - - LU Latch-up (Per JESD78) 1/6/0 1/6/0 - - - TC Temperature Cycle, -65/150C 500 Cycles - - 3/231/0 1/77/0 2/154/0 WBP Bond Pull Wires 1/76/0 1/76/0 - 1/30/0 2/60/0 WBS Ball Bond Shear Wires 1/76/0 1/76/0 - 1/30/0 2/60/0	HTOL	Life Test, 135C	635 Hours	-	-	3/231/0	-	-
HTSL Storage Bake, 170C 420 Hours - 3/231/0 - - - LU Latch-up (Per JESD78) 1/6/0 1/6/0 - - - - TC Temperature Cycle, -65/150C 500 Cycles - - 3/231/0 1/77/0 2/154/0 WBP Bond Pull Wires 1/76/0 1/76/0 - 1/30/0 2/60/0 WBS Ball Bond Shear Wires 1/76/0 1/76/0 - 1/30/0 2/60/0	HTSL	Storage Bake	500 Hours	-	-	-	1/45/0	2/90/0
LU Latch-up JESD78) 1/6/0 1/6/0 - <td>HTSL</td> <td>Storage Bake,</td> <td>420 Hours</td> <td>-</td> <td>-</td> <td>3/231/0</td> <td>-</td> <td>-</td>	HTSL	Storage Bake,	420 Hours	-	-	3/231/0	-	-
TC 500 Cycles - - 3/231/0 1/77/0 2/154/0 WBP Bond Pull Wires 1/76/0 1/76/0 - 1/30/0 2/60/0 WBS Ball Bond Shear Wires 1/76/0 1/76/0 - 1/30/0 2/60/0	LU	Latch-up		1/6/0	1/6/0	-	-	-
WBS Ball Bond Shear Wires 1/76/0 1/76/0 - 1/30/0 2/60/0	тс		500 Cycles	-	-	3/231/0	1/77/0	2/154/0
	WBP	Bond Pull	Wires	1/76/0	1/76/0	-	1/30/0	2/60/0
			Wires	1/76/0	1/76/0	-	1/30/0	2/60/0

- QBS: Qual By Similarity

- Qual Device SN65HVD11QDR is qualified at LEVEL1-260C

- Qual Device SN65HVD12DR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

Qualification Report

Approve Date 09-Mar-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>BOND6-</u> <u>SN65HVD3085EDR</u>	Qual Device: <u>BOND6-</u> <u>SN65HVD3085EDGKR</u>	Qual Device: <u>BOND8-</u> <u>SN65HVD3088EDR</u>	Qual Device: <u>BOND8-</u> <u>SN65HVD3088EDGKR</u>	QBS Process Reference: <u>TPS51217DSC</u>	QBS Package Reference: <u>TCAN1044VDQ1(PG2.0)</u>	QBS Package Reference: TCAN1044VD Q1(PG1.1/PG1.0)
AC	Autoclave 121C	96 Hours	-	-	-	-	6/462/0	1/77/0	2/154/0
CDM	ESD - CDM	1500 V	1/3/0	1/3/0	1/3/0	1/3/0	3/9/0	-	-
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	-	1/30/0	-	3/60/0	2/60/0	-
HAST	Biased HAST 130C/85%RH	96 Hours	-	-	-	-	3/231/0	1/77/0	2/154/0
HBM	ESD - HBM	4000 V	1/3/0	-	1/3/0	-	-	-	-
HTOL	Life Test, 135C	635 Hours	-	-	-	-	3/231/0	-	-
HTSL	High Temp Storage Bake 175C	500 Hours	-	-	-	-	-	1/45/0	2/90/0
LI	Lead Pull to Destruction	Leads	-	-	-	-	-	-	1/24/0
LU	Latch-up	(per JESD78)	1/6/0	-	1/6/0	-	3/18/0	-	-
PD	Physical Dimensions	Cpk>1.67	-	-	-	-	-	1/10/0	2/20/0
SD	Surface Mount Solderability	Pb Free Solder	-	-	-	-	-	-	1/15/0
SD	Surface Mount Solderability	Pb Solder	-	-	-	-	-	-	1/15/0
тс	Temperature Cycle -65/150C	500 Cycles	-	-	-	-	3/231/0	1/77/0	2/154/0
WBP	Bond Pull	Wires	1/76/0	1/76/0	1/76/0	1/76/0	-	1/30/0	2/60/0
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	1/76/0	1/76/0	-	1/30/0	2/60/0

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	QBS Package Reference: <u>TP S62842DGR</u>
AC	Autoclave 121C	96 Hours	3/231/0
CDM	ESD - CDM	1500 V	1/3/0
ED	Electrical Characterization	Per Datasheet Parameters	-
HAST	Biased HAST, 130C/85%RH	96 Hours	3/231/0
HBM	ESD - HBM	4000 V	1/3/0
HTOL	Life Test, 135C	635 Hours	-
HTSL	High Temp Storage Bake 175C	500 Hours	-
LI	Lead Pull to Destruction	Leads	-
LU	Latch-up	(per JESD78)	1/3/0
PD	Physical Dimensions	Cpk>1.67	-
PKG	Lead Finish Adhesion	0 Hr	3/45/0
SD	Solderability test	4	3/66/0
SD	Surface Mount Solderability	Pb Free Solder	-
SD	Surface Mount Solderability	Pb Solder	-
TC	Temperature Cycle, -65/150C	500 Cycles	3/231/0
WBP	Bond Pull	Wires	-
WBS	Ball Bond Shear	Wires	-

- QBS: Qual By Similarity

Qual Device BOND6-SN65HVD3085EDGKR is qualified at LEVEL1-260C

- Qual Device BOND8-SN65HVD3088EDGKR is qualified at LEVEL1-260C - Qual Device BOND6- SN65HVD3085EDR is qualified at LEVEL1-260C

- Qual Device BOND8- SN65HVD3088EDR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours - The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

Qualification Report

Approve Date 22-Feb-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>SN65HVD10QDR</u>	QBS Process Reference: TPS51217DSC	QBS Package Reference: <u>TCAN1044VDQ1(PG2.0)</u>	QBS Package Reference: TCAN1044VD Q1(PG1.1/PG1.0)
AC	Autoclave 121C	96 Hours	-	6/462/0	1/77/0	2/154/0
CDM	ESD - CDM	1500 V	1/3/0	3/9/0	-	-
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	-	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	1/77/0	2/154/0
HBM	ESD – HBM (Bus Pins)	16000 V	1/3/0	-	-	-
HBM	ESD – HBM (All Pins)	4000 V	1/3/0	-	-	-
HTOL	Life Test, 135C	635 Hours	-	3/231/0	-	-
HTSL	High Temp Storage Bake 175C	500 Hours	-	-	1/45/0	2/90/0
LI	Lead Pull to Destruction	Leads	-	-	-	1/24/0
LU	Latch-up	(per JESD78)	1/6/0	3/18/0	-	-
MSL	Moisture Sensitivity, L1	L1-260C	1/12/0	-	-	-
SD	Surface Mount Solderability	Pb Free Solder	-	-	-	1/15/0
SD	Surface Mount Solderability	Pb Solder	-	-	-	1/15/0
TC	Temperature Cycle -65/150C	500 Cycles	-	3/231/0	1/77/0	2/154/0
WBP	Bond Pull	Wires	1/76/0	-	-	-
WBS	Ball Bond Shear	Wires	1/76/0	-	-	-

QBS: Qual By Similarity

- Qual Device SN65HVD10QDR is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave. Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

For questions regarding this notice, e-mails can be sent to the contact shown below or your local Field Sales Representative.

Location	E-Mail		
WW Change Management Team	PCN_ww_admin_team@list.ti.com		

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